L Number	Hits		DB	Time stamp
15	41178	gate and (capacitor or capacitance or	USPAT;	2003/08/20 23:03
		capacitive\$2) and (insulat\$4 or	US-PGPUB;	
		dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island) or transistor or MOSFET\$1 or		
1.0	47005	FET\$1)	HODAM.	2003/00/20 23-03
16	47885	gate and (capacitor or capacitance or	USPAT; US-PGPUB;	2003/08/20 23:03
		capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island) or transistor\$1 or MOSFET\$1 or	EFO, OFO	
		FET\$1 or JFET\$1)		
17	39044	gate and (capacitor or capacitance or	USPAT;	2003/08/20 23:03
	00011	capacitive\$2) and (insulat\$4 or	US-PGPUB;	
		dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island\$1) or transistor\$1 or MOSFET\$1 or	·	
į		FET\$1 or JFET\$1)		
18	24880	(313/\$7.ccls. or 250/\$7.ccls. or	USPAT;	2003/08/20 23:05
		257/\$7.ccls. or 315/\$7.ccls.) and (gate	US-PGPUB;	
		and (capacitor or capacitance or	EPO; JPO	
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
į		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1))		
19	2757	((light\$4 adj2 emit\$5) or EL or OLED or	USPAT;	2003/08/20 23:07
		electroluminescen\$4 or luminescen\$4) and	US-PGPUB;	
1		((313/\$7.ccls. or 250/\$7.ccls. or	EPO; JPO	
		257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1)))		
20	1958	((light\$4 adj2 emit\$5) or EL or OLED or	USPAT;	2003/08/20 23:07
		electroluminescen\$4 or luminescen\$4) and	EPO; JPO	
		((313/\$7.ccls. or 250/\$7.ccls. or		ļ
		257/\$7.ccls. or 315/\$7.ccls.) and (gate		
		and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		1
		dielectric\$3) and ((semiconduct\$3 near2		
İ		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1)))		/ /
21	557	channel\$1 and (impurit\$3) and (((light\$4	USPAT;	2003/08/20 23:07
		adj2 emit\$5) or EL or OLED or	US-PGPUB;	
		electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or	EPO; JPO	
,				
		257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or		
ļ		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
[		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1))))		
22	163	cathode and anode and (channel\$1 and	USPAT;	2003/08/20 23:08
	•	(impurit\$3) and (((light\$4 adj2 emit\$5) or	US-PGPUB;	
		EL or OLED or electroluminescen\$4 or	EPO; JPO	
į		luminescen\$4) and ((313/\$7.ccls. or		
		250/\$7.ccls. or 257/\$7.ccls. or		
		315/\$7.ccls.) and (gate and (capacitor or		
-		capacitance or capacitive\$2) and		
		(insulat\$4 or dielectric\$3) and		
		((semiconduct\$3 near2 island) or		
1		transistor\$1 or MOSFET\$1 or FET\$1 or		
		JFET\$1)))))	J	l

L Number	Hits	Search Text	DB	Time stamp
15	41178	gate and (capacitor or capacitance or	USPAT;	2003/08/20 23:03
-	124.0	capacitive\$2) and (insulat\$4 or	US-PGPUB;	
		dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island) or transistor or MOSFET\$1 or	,	
		FET\$1)		
16	47885	gate and (capacitor or capacitance or	USPAT;	2003/08/20 23:03
		capacitive\$2) and (insulat\$4 or	US-PGPUB;	
		dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1)		
17	39044	gate and (capacitor or capacitance or	USPAT;	2003/08/20 23:03
		capacitive\$2) and (insulat\$4 or	US-PGPUB;	
		dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island\$1) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1)		
18	24880	(313/\$7.ccls. or 250/\$7.ccls. or	USPAT;	2003/08/20 23:05
		257/\$7.ccls. or 315/\$7.ccls.) and (gate	US-PGPUB;	
		and (capacitor or capacitance or	EPO; JPO	
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
1.0	0757	FET\$1 or JFET\$1))	HODAM.	2002/00/00 22:07
19	2757	1	USPAT;	2003/08/20 23:07
		electroluminescen\$4 or luminescen\$4) and	US-PGPUB;	
		((313/\$7.ccls. or 250/\$7.ccls. or	EPO; JPO	
		257/\$7.ccls. or 315/\$7.ccls.) and (gate		
		and (capacitor or capacitance or capacitive \$2) and (insulat \$4 or		
		dielectric\$3) and (!semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or	1	
		FET\$1 or JFET\$1)))		
20	1958	((light\$4 adj2 emit\$5) or EL or OLED or	USPAT;	2003/08/20 23:09
20	. 1330	electroluminescen\$4 or luminescen\$4) and	EPO; JPO	2003,00,20 23:03
		((313/\$7.ccls. or 250/\$7.ccls. or	220, 020	
		257/\$7.ccls. or 315/\$7.ccls.) and (gate		
		and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1)))		
21	557	channel\$1 and (impurit\$3) and (((light\$4	USPAT;	2003/08/20 23:10
		adj2 emit\$5) or EL or OLED or	US-PGPUB;	
		electroluminescen\$4 or luminescen\$4) and	EPO; JPO	
		((313/\$7.ccls. or 250/\$7.ccls. or		
		257/\$7.ccls. or 315/\$7.ccls.) and (gate		
		and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
, ,	1.00	FET\$1 or JFET\$1))))	HCDAM.	2003/08/20 23:10
22	163	1	USPAT;	2003/08/20 23:10
		(impurit\$3) and (((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or	US-PGPUB; EPO; JPO	
		luminescen\$4) and ((313/\$7.ccls. or	E.U, UEU	
		250/\$7.ccls. or 257/\$7.ccls. or		
		315/\$7.ccls.) and (gate and (capacitor or	1	
		capacitance or capacitive\$2) and		
		(insulat\$4 or dielectric\$3) and		
		((semiconduct\$3 near2 island) or	1	
		transistor\$1 or MOSFET\$1 or FET\$1 or		
		JFET\$1)))))		
				1
23	2050	((light\$4 adj2 emit\$5) or EL or OLED or	USPAT;	2003/08/20 23:09
23	2050	((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4 or	USPAT; EPO; JPO	2003/08/20 23:09
23	2050	electroluminescen\$4 or luminescen\$4 or luminous) and ((313/\$7.ccls. or		2003/08/20 23:09
23	2050	electroluminescen\$4 or luminescen\$4 or luminous) and ((313/\$7.ccls. or 250/\$7.ccls. or		2003/08/20 23:09
23	2050	electroluminescen\$4 or luminescen\$4 or luminous) and ((313/\$7.ccls. or 250/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or		2003/08/20 23:09
23	2050	electroluminescen\$4 or luminescen\$4 or luminous) and ((313/\$7.ccls. or 250/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and		2003/08/20 23:09
23	2050	electroluminescen\$4 or luminescen\$4 or luminous) and ((313/\$7.ccls. or 250/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and		2003/08/20 23:09
23	2050	electroluminescen\$4 or luminescen\$4 or luminous) and ((313/\$7.ccls. or 250/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or		2003/08/20 23:09
23	2050	electroluminescen\$4 or luminescen\$4 or luminous) and ((313/\$7.ccls. or 250/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and		2003/08/20 23:09

			1==:	T
24	163	channel\$1 and (impurit\$3) and (cathode and anode and (channel\$1 and (impurit\$3) and (((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)))))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:10
25	525	1	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:10
26	156		USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:10